

Synchronous Regulator with Bypass Mode, TINYBOOST[®], 2.5 MHz, 1500 mA

FAN48630J

Description

The FAN48630J allows systems to take advantage of new battery chemistries that can supply significant energy when the battery voltage is lower than the required voltage for system power ICs. By combining built-in power transistors, synchronous rectification, and low supply current; this IC provides a compact solution for systems using advanced Li-Ion battery chemistries.

The FAN48630J is a boost regulator designed to provide a minimum output voltage ($V_{OUT(MIN)}$) from a single-cell Li-Ion battery, even when the battery voltage is below system minimum. Output voltage regulation is guaranteed to a maximum load current of 1500 mA. Quiescent current in Shutdown Mode is less than 3 μ A, which maximizes battery life. The regulator transitions smoothly between Bypass and normal Boost Mode. The device can be forced into Bypass Mode to reduce quiescent current.

The FAN48630J is available in a 16-bump, 0.4 mm pitch, Wafer-Level Chip-Scale Package (WLCSP).

Features

- 3 External Components: 0.47 μ H Inductor and 0603 Case Size Input and Output Capacitors
- Input Voltage Range: 2.35 V to 5.5 V
- Fixed Output Voltage Option: 3.15 V/3.6 V
- Up to 96% Efficient
- True Bypass Operation when $V_{IN} >$ Target V_{OUT}
- Internal Synchronous Rectifier
- Soft-Start with True Load Disconnect
- Forced Bypass Mode
- V_{SEL} Control to Optimize Target V_{OUT}
- Short-Circuit Protection
- Low Operating Quiescent Current
- 16-Bump, 0.4 mm Pitch WLCSP

Applications

- Boost for Low-Voltage Li-ion Batteries, Brownout Prevention, Boosted Audio, USB OTG, and LTE / 3G RF Power
- Cell Phones, Smart Phones, Portable Instruments



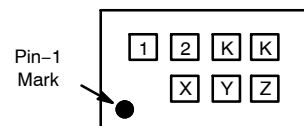
ON Semiconductor[®]

www.onsemi.com



WLCSP16 1.78x1.78x0.586
CASE 567SY

MARKING DIAGRAM



- 12 = Alphanumeric Device Marking
- KK = Lot Rune Code
- X = Alphabetical Year Code
- Y = 2-weeks Date Code
- Z = Assembly Plant Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

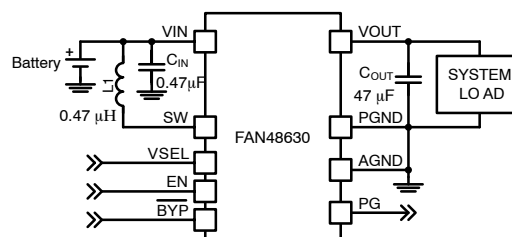


Figure 1. Typical Application

FAN48630J

Table 1. ORDERING INFORMATION

Part Number	Output Voltage V _{SELO} /V _{SEL1}	Operating Temperature	Package	Shipping†	Device Marking
FAN48630BUC31JX	3.15 V/3.60 V	-40 to 85°C	WLCSP	Tape & Reel	JH

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL APPLICATION

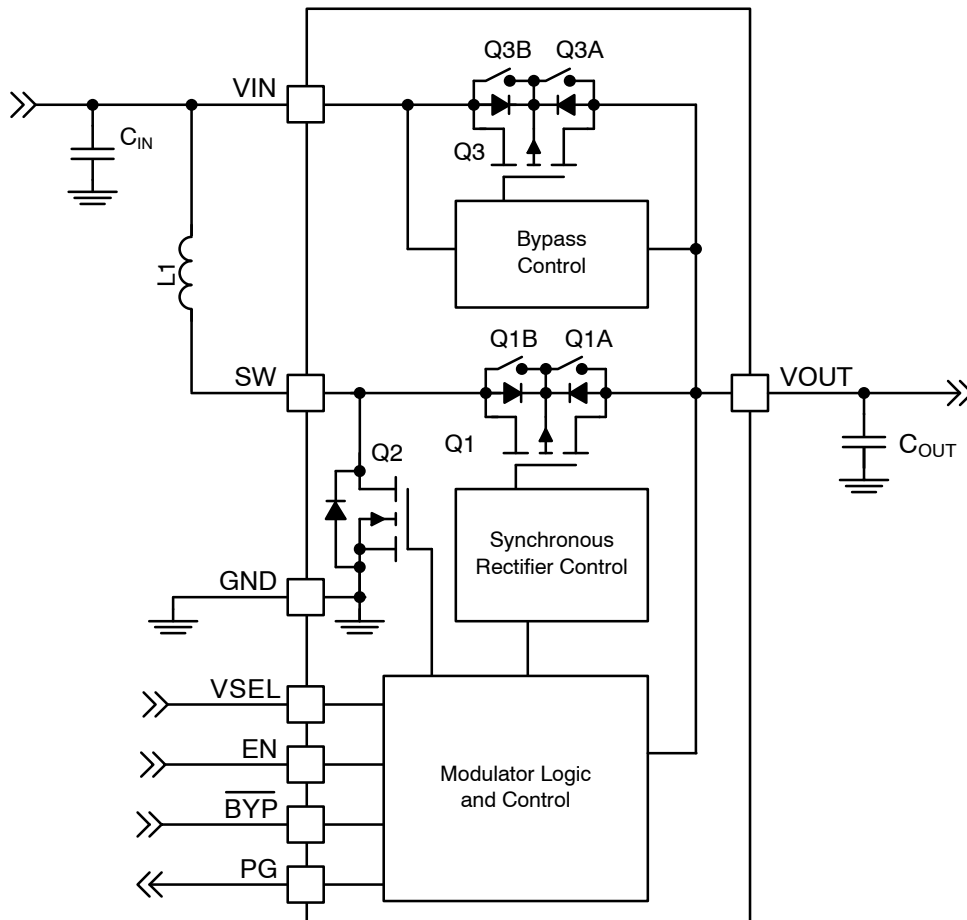


Figure 2. Typical Application Block Diagram

Table 2. RECOMMENDED COMPONENTS

Component	Description	Vendor	Parameter	Typ.	Unit
L1	0.47 μ H, 30%	Toko: DFE201612C DFR201612C Cyntec: PIFE20161B	L	0.47	μ H
C _{IN}	4.7 μ F, 10%, 6.3 V, X5R, 0603 (1608)	Murata: GRM188R60J475K TDK: C1608X5R0J475K	C	4.7	μ F
C _{OUT}	47 μ F, 20%, 6.3 V, X5R, 0603 (1608)	Samsung: CL10A476MQ8CZNE	C	47	μ F

FAN48630J

PIN CONFIGURATION

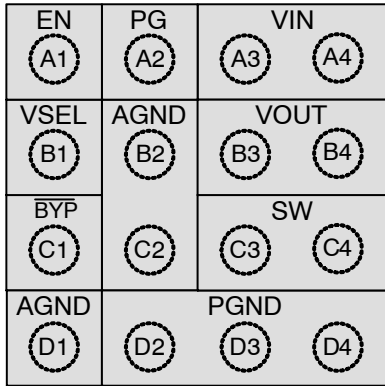


Figure 3. Top Through View (Bumps Down)

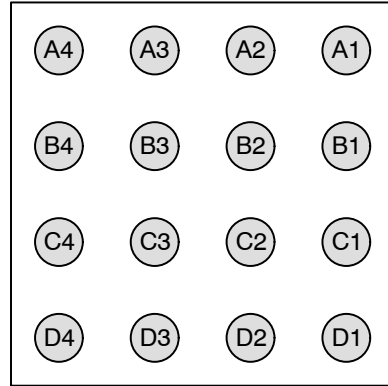


Figure 4. Bottom View

Table 3. PIN DEFINITIONS

Pin #	Name	Description
A1	EN	<u>Enable</u> . When this pin is HIGH, the circuit is enabled (Note 1).
A2	PG	<u>Power Good</u> . This is an open-drain output. PG is actively pulled LOW if output falls out of regulation due to overload or if thermal protection threshold is exceeded.
A3–A4	VIN	<u>Input Voltage</u> . Connect to Li–Ion battery input power source.
B1	VSEL	<u>Output Voltage Select</u> . When boost is running, this pin can be used to select output voltage.
B2, C2, D1	AGND	<u>Analog Ground</u> . This is the signal ground reference for the IC. All voltage levels are measured with respect to this pin.
B3–B4	VOUT	<u>Output Voltage</u> . Place C_{OUT} as close as possible to the device.
C1	BYP	<u>Bypass</u> . This pin can be used to activate Forced Bypass Mode. When this pin is LOW, the bypass switches (Q3 and Q1) are turned on and the IC is otherwise inactive.
C3–C4	SW	<u>Switching Node</u> . Connect to inductor.
D2–D4	PGND	<u>Power Ground</u> . This is the power return for the IC. The C_{OUT} bypass capacitor should be returned with the shortest path possible to these pins.

1. Do not connect the EN pin to VIN. A logic voltage of 1.8 V should control the EN pin and enable/disable the device.

FAN48630J

Table 4. ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Min.	Max.	Unit	
V _{IN}	V _{IN} Input Voltage	-0.3	6.5	V	
V _{OUT}	V _{OUT} Output Voltage		6.0	V	
	SW Node				
	DC	-0.3	8.0	V	
	Transient: 10 ns, 3 MHz	-1.0	8.0	V	
	Other Pins	-0.3	6.5 (Note 2)	V	
ESD	Electrostatic Discharge Protection Level	Human Body Model per JESD22-A114		2.0	kV
		Charged Device Model per JESD22-C101		1.5	kV
T _J	Junction Temperature	-40	+150	°C	
T _{STG}	Storage Temperature	-65	+150	°C	
T _L	Lead Soldering Temperature, 10 Seconds		+260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Lesser of 6.5 V or V_{IN} + 0.3 V.

Table 5. RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V _{IN}	Supply Voltage	2.35	5.5	V
I _{OUT}	Output Current	0	1500	mA
T _A	Ambient Temperature	-40	+85	°C
T _J	Junction Temperature	-40	+125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 6. THERMAL PROPERTIES

Symbol	Parameter	Typ.	Unit
θ _{JA}	Junction-to-Ambient Thermal Resistance	80	°C/W
θ _{JB}	Junction-to-Board Thermal Resistance	42	

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer Fairchild evaluation boards (1 oz copper on all layers). Special attention must be paid not to exceed junction temperature T_{J(max)} at a given ambient temperature T_A.

FAN48630J

Table 7. ELECTRICAL CHARACTERISTICS Recommended operating conditions, unless otherwise noted, circuit per Figure 1, $V_{IN} = 2.35\text{ V to }5.5\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$. Typical values are given at $V_{IN} = 3.0\text{ V}$ and $T_A = 25^\circ\text{C}$.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
I_Q	V_{IN} Quiescent Current	Bypass Mode $V_{OUT} = 3.15\text{ V}$, $V_{IN} = 4.2\text{ V}$		140	190	μA
		Boost Mode $V_{OUT} = 3.15\text{ V}$, $V_{IN} = 2.5\text{ V}$		150	250	μA
		Shutdown: $EN = 0$, $V_{IN} = 3.0\text{ V}$		1.5	5.0	μA
		Forced Bypass Mode, $V_{IN} = 3.5\text{ V}$		4	10	μA
I_{LK}	V_{OUT} to V_{IN} Reverse Leakage	$V_{OUT} = 3.6\text{ V}$, $EN = 0$		0.2	1.0	μA
I_{LK_OUT}	V_{OUT} Leakage Current	$V_{OUT} = 0$, $EN = 0$, $V_{IN} = 4.2\text{ V}$		0.1	1.0	μA
V_{UVLO}	Under-Voltage Lockout	V_{IN} Rising		2.20	2.35	V
V_{UVLO_HYS}	Under-Voltage Lockout Hysteresis			200		mV
$V_{PG(OL)}$	PG Low	$I_{PG} = 5\text{ mA}$			0.4	V
I_{PG_LK}	PG Leakage Current				1	μA
V_{IH}	Logic Level High EN , $VSEL$, BYP		1.2			V
V_{IL}	Logic Level Low EN , $VSEL$, BYP				0.4	V
R_{LOW}	Logic Control Pin Pull Downs (LOW Active)	\overline{BYP} , $VSEL$, EN		300		$\text{k}\Omega$
I_{PD}	Weak Current Source Pull-Down	BYP , $VSEL$, EN		100		nA
V_{REG}	Output Voltage Accuracy	$2.35\text{ V} \leq V_{IN} \leq V_{OUT_TARGET} - 100\text{ mV}$, DC, 0 to 1500 mA	-2		4	%
f_{SW}	Switching Frequency	$V_{IN} = 2.7\text{ V}$, $V_{OUT} = 3.15\text{ V}$, Load = 1000 mA	2.0	2.5	3.0	MHz
I_V_LIM	Boost Valley Current Limit	$V_{IN} = 2.6\text{ V}$	2.6	2.9	3.1	A
V_{OVP}	Output Over-Voltage Protection Threshold			6.0	6.3	V
V_{OVP_HYS}	Output Over-Voltage Protection Hysteresis			300		mV
$R_{DS(ON)N}$	N-Channel Boost Switch $R_{DS(ON)}$	$V_{IN} = 3.5\text{ V}$, $V_{OUT} = 3.5\text{ V}$		85	120	$\text{m}\Omega$
$R_{DS(ON)P}$	P-Channel Sync Rectifier $R_{DS(ON)}$	$V_{IN} = 3.5\text{ V}$, $V_{OUT} = 3.5\text{ V}$		65	85	$\text{m}\Omega$
$R_{DS(ON)P_BYP}$	P-Channel Bypass Switch $R_{DS(ON)}$	$V_{IN} = 3.5\text{ V}$, $V_{OUT} = 3.5\text{ V}$		65	85	$\text{m}\Omega$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

FAN48630J

Table 8. SYSTEM CHARACTERISTICS

The following table is verified by design and verified while using the following external components: L = 0.47 μ H, DFE201612C-R47M (Toko), C_{IN} = 4.7 μ F, 0603 (1608 metric), C1608X5R0J475K (TDK), C_{OUT} = 47 μ F, 0603 (1608 metric), CL10A476MQ8CZNE (Samsung). These parameters are not verified in production. Minimum and maximum values are at V_{IN} = 2.5 V to 5.5 V, T_A = -40°C to +85°C; circuit per Figure 1, unless otherwise noted. Typical values are at T_A = 25°C, V_{IN} = 3.0 V, V_{OUT} = 3.6 V, V_{EN} = 1.8 V.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
ΔV_{OUT_LOAD}	Load Regulation	I _{OUT} = 0 A to 1 A, V _{IN} = 3.0 V		80		mV/A
ΔV_{OUT_LINE}	Line Regulation	2.7 V \leq V _{IN} \leq 3.0 V, I _{OUT} = 1 A		7		mV/V
V _{OUT_RIPPLE}	Ripple Voltage	V _{IN} = 3.0 V, V _{OUT} = 3.6 V, I _{OUT} = 800 mA, PWM Mode		10		mV
		V _{IN} = 3.0 V, V _{OUT} = 3.6 V, I _{OUT} = 50 mA, PFM Mode		11		
η	Efficiency	V _{IN} = 2.5 V, V _{OUT} = 3.15 V, I _{OUT} = 20 mA, PFM		90		%
		V _{IN} = 3.0 V, V _{OUT} = 3.15 V, I _{OUT} = 500 mA, PWM		96		
		V _{IN} = 3.0 V, V _{OUT} = 3.6 V, I _{OUT} = 600 mA, PWM		93		
T _{SS}	Soft-Start	EN High to 95% of Target_ V _{OUT} . R _L = 50 Ω		550		μ s
$\Delta V_{OUT_LOAD_TRX}$	Load Transient	V _{IN} = 3.0 V, I _{OUT} = 0.5 A \leftrightarrow 1 A, T _R = T _F = 1 μ s		\pm 95		mV
$\Delta V_{OUT_LINE_TRX}$	Line Transient	V _{IN} = 2.5 V \leftrightarrow 3.0 V, T _R = T _F = 10 μ s, I _{OUT} = 300 mA		\pm 15		mV

FAN48630J

TYPICAL CHARACTERISTICS

Unless otherwise specified; $V_{IN} = 3.0\text{ V}$, $V_{OUT} = 3.6\text{ V}$, and $T_A = 25^\circ\text{C}$; circuit and components according to Figure 1.

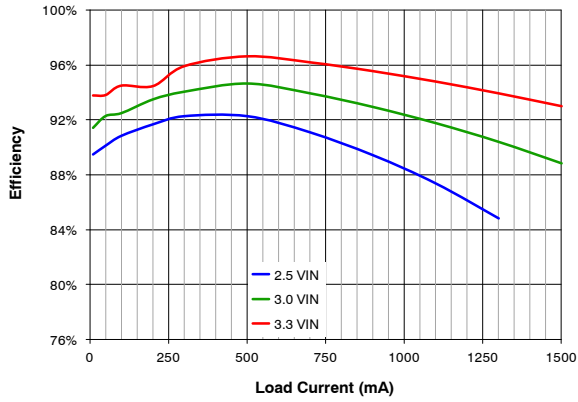


Figure 5. Efficiency vs. Load Current and Input Voltage

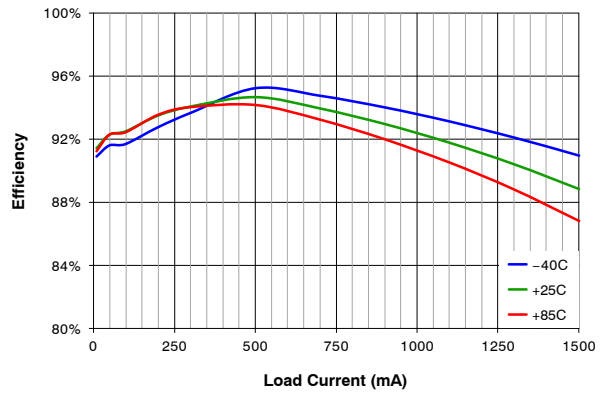


Figure 6. Efficiency vs. Load Current and Temperature

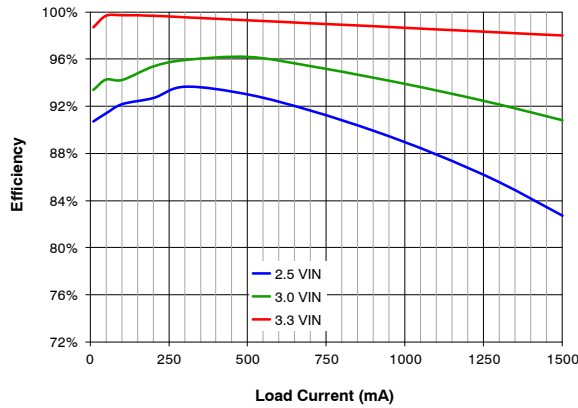


Figure 7. Efficiency vs. Load Current and Input Voltage, $V_{OUT} = 3.15\text{ V}$

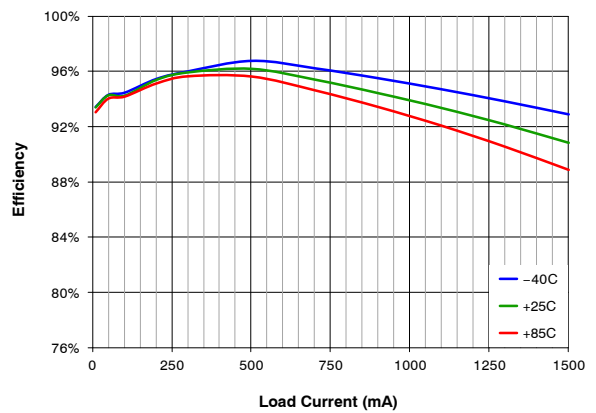


Figure 8. Efficiency vs. Load Current and Temperature, $V_{OUT} = 3.15\text{ V}$

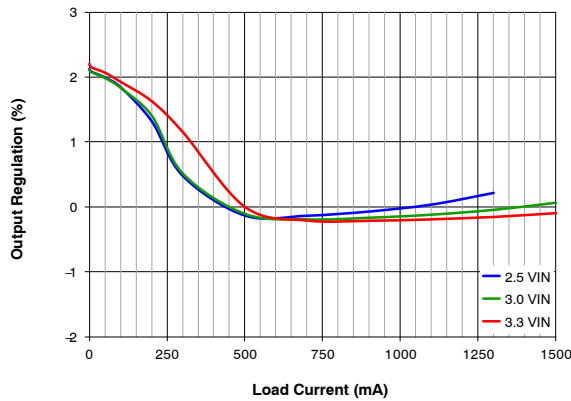


Figure 9. Output Regulation vs. Load Current and Input Voltage

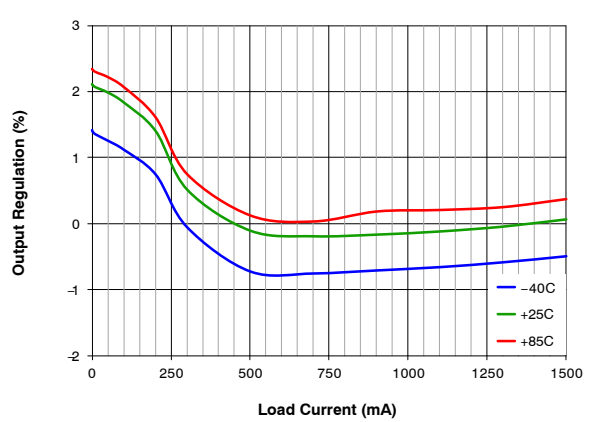


Figure 10. Output Regulation vs. Load Current and Temperature

FAN48630J

TYPICAL CHARACTERISTICS (CONTINUED)

Unless otherwise specified; $V_{IN} = 3.0\text{ V}$, $V_{OUT} = 3.6\text{ V}$, and $T_A = 25^\circ\text{C}$; circuit and components according to Figure 1.

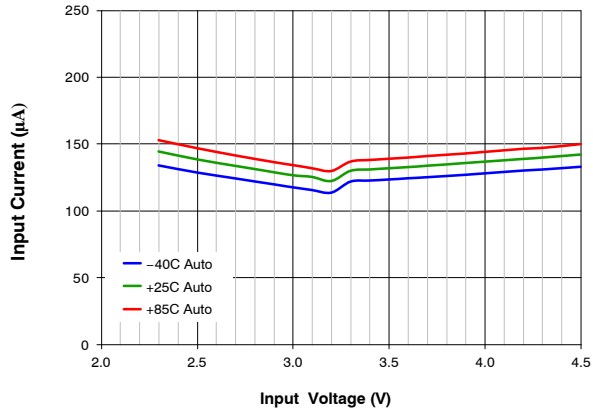


Figure 11. Quiescent Current vs. Input Voltage and Temperature, $V_{OUT} = 3.15\text{ V}$, Auto Mode

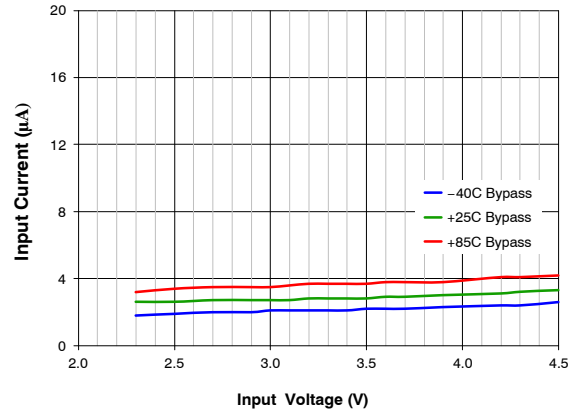


Figure 12. Quiescent Current vs. Input Voltage and Temperature, $V_{OUT} = 3.15\text{ V}$, Forced Bypass Mode

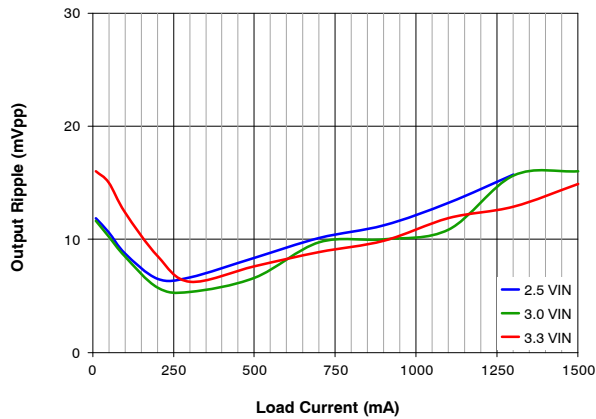


Figure 13. Output Ripple vs. Load Current and Input Voltage

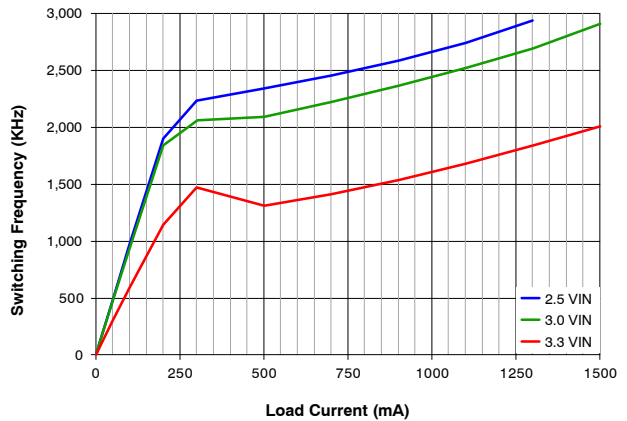


Figure 14. Frequency vs. Load Current and Input Voltage

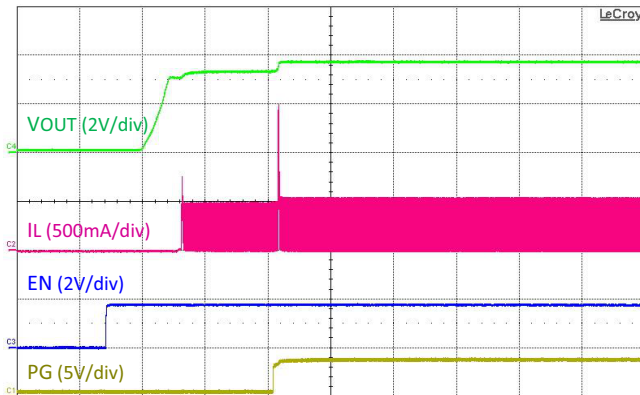


Figure 15. Startup, 50 Ω Load

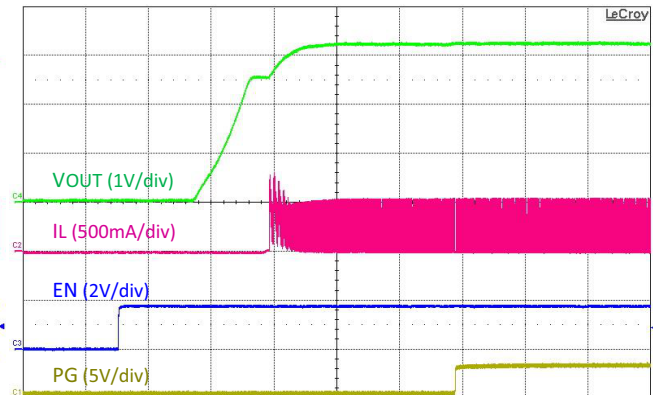


Figure 16. Startup, 50 Ω Load, $V_{IN} = 2.5\text{ V}$, $V_{OUT} = 3.15\text{ V}$

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TYPICAL CHARACTERISTICS (CONTINUED)

Unless otherwise specified, $V_{IN} = 3.0\text{ V}$; $V_{OUT} = 3.6\text{ V}$, and $T_A = 25^\circ\text{C}$; circuit and components according to Figure 1.

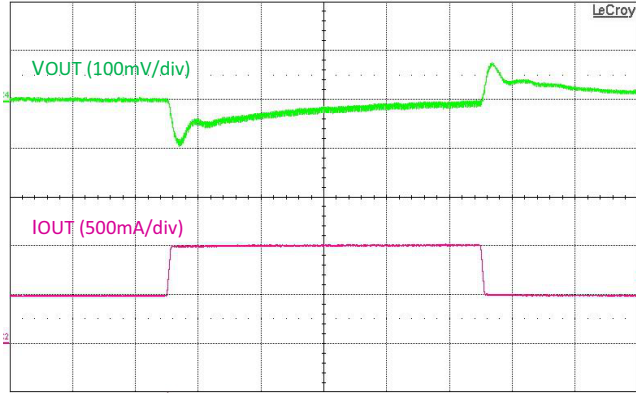


Figure 17. Load Transient, $I_{OUT} = 500 \leftrightarrow 1000\text{ mA}$, $1\ \mu\text{s}$ Edge

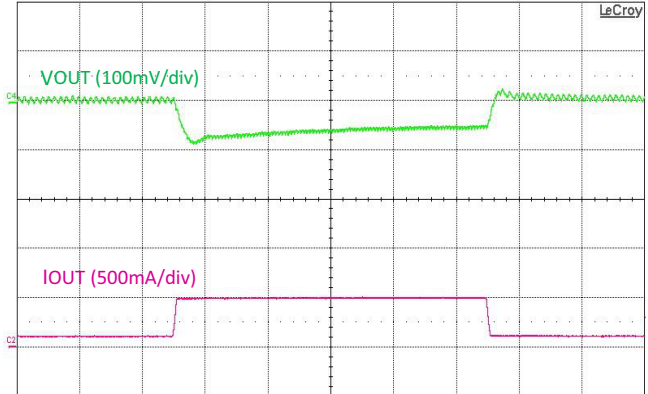


Figure 18. Load Transient, $I_{OUT} = 100 \leftrightarrow 500\text{ mA}$, $1\ \mu\text{s}$ Edge, $V_{OUT} = 3.15\text{ V}$

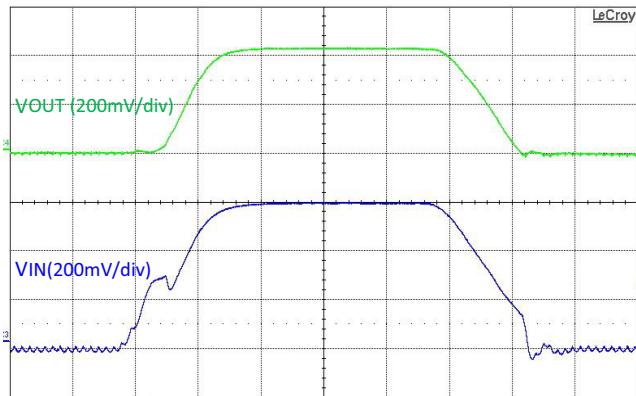


Figure 19. Line Transient, $V_{IN} = 3.0\text{ V} \leftrightarrow 3.6\text{ V}$, $10\ \mu\text{s}$ Edge, $I_{OUT} = 500\text{ mA}$, $V_{OUT} = 3.15\text{ V}$

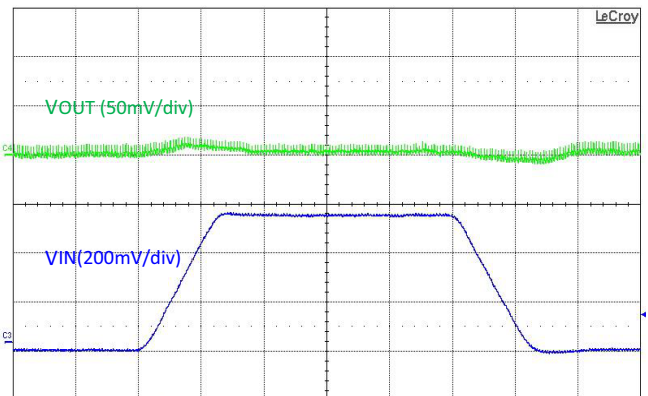


Figure 20. Line Transient, $V_{IN} = 2.5\text{ V} \leftrightarrow 3.0\text{ V}$, $10\ \mu\text{s}$ Edge, $I_{OUT} = 300\text{ mA}$

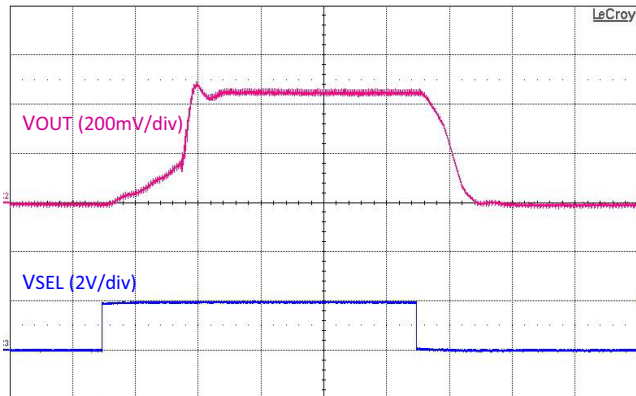


Figure 21. V_{SEL} Step, $V_{IN} = 3\text{ V}$, $V_{OUT} = 3.15 \leftrightarrow 3.6\text{ V}$, $I_{OUT} = 500\text{ mA}$

CIRCUIT DESCRIPTION

FAN48630J is a synchronous boost regulator, typically operating at 2.5 MHz in Continuous Conduction Mode (CCM), which occurs at moderate to heavy load current and low V_{IN} voltages. The regulator includes a Bypass Mode that activates when V_{IN} is above the boost regulator’s setpoint.

In anticipation of a heavy load transition, the setpoint can be adjusted upward by fixed amounts with the VSEL pin to reduce the required system headroom during lighter-load operation to save power.

Table 9. Operating States

Mode	Description	Invoked When
LIN	Linear Startup	$V_{IN} > V_{OUT}$
SS	Boost Soft-Start	$V_{OUT} < V_{OUT(MIN)}$
BST	Boost Operating Mode	$V_{OUT} = V_{OUT(MIN)}$
BPS	True Bypass Mode	$V_{IN} > V_{OUT(MIN)}$

Boost Mode

The FAN48630J uses a current-mode modulator to achieve excellent transient response and smooth transitions between CCM and Discontinuous Conduction Mode (DCM) operation. During CCM operation, the device maintains a switching frequency of about 2.5 MHz. In light-load operation (DCM), frequency is reduced to maintain high efficiency.

Table 10. Boost Startup Sequence

Start State	Entry	Exit	End State	Timeout (µs)
LIN1	$V_{IN} > UVLO$, EN = 1	$V_{OUT} > V_{IN}-300\text{ mV}$	SS	
			LIN2	512
LIN2	LIN1 Exit	$V_{OUT} > V_{IN}-300\text{ mV}$	SS	
		TIMEOUT	FAULT	1024
SS	LIN1 or LIN2 Exit	$V_{OUT} = V_{OUT(MIN)}$	BST	
		OVERLOAD TIMEOUT	FAULT	64

Shutdown and Startup

If EN is LOW, all bias circuits are off and the regulator is in Shutdown Mode. During shutdown, current flow is prevented from V_{IN} to V_{OUT} , as well as reverse flow from V_{OUT} to V_{IN} . During startup, it is recommended to keep DC current draw below 500 mA.

LIN State

When EN is HIGH and $V_{IN} > UVLO$, the regulator attempts to bring V_{OUT} within 300 mV of V_{IN} using the

internal fixed current source from V_{IN} (Q3). The current is limited to LIN1 set point.

If V_{OUT} reaches $V_{IN}-300\text{ mV}$ during LIN1 Mode, the SS state is initiated. Otherwise, LIN1 times out after 512 µs and LIN2 Mode is entered.

In LIN2 Mode, the current source is incremented to 2 A. If V_{OUT} fails to reach $V_{IN}-300\text{ mV}$ after 1024 µs, a fault condition is declared.

SS State

Upon the successful completion of the LIN state ($V_{OUT} \geq V_{IN}-300\text{ mV}$), the regulator begins switching with boost pulses current limited to 50% of nominal level.

During SS state, V_{OUT} is ramped up by stepping the internal reference. If V_{OUT} fails to reach regulation during the SS ramp sequence for more than 64 µs, a fault condition is declared. If large C_{OUT} is used, the reference is automatically stepped slower to avoid excessive input current draw.

BST State

This is a normal operating state of the regulator.

BPS State

If V_{IN} is above V_{REG} when the SS Mode successfully completes, the device transitions directly to BPS Mode.

FAULT State

The regulator enters the FAULT state under any of the following conditions:

- V_{OUT} fails to achieve the voltage required to advance from LIN state to SS state.
- V_{OUT} fails to achieve the voltage required to advance from SS state to BST state.
- Boost current limit triggers for 2 ms during the BST state.
- V_{DS} protection threshold is exceeded during BPS state.
- V_{IN} drops below UVLO threshold.

Once a FAULT is triggered, the regulator stops switching and presents a high-impedance path between V_{IN} to V_{OUT} . After waiting 20 ms, a restart is attempted.

Power Good

Power good is 0 FAULT, 1 POWER GOOD, open-drain output.

The Power good pin is provided for signaling the system when the regulator has successfully completed soft-start and no faults have occurred. Power good also functions as an early warning flag for high die temperature and overload conditions.

- PG is released HIGH when the soft-start sequence is successfully completed.
- PG is pulled LOW when PMOS current limit has triggered for 64 µs OR the die the temperature exceeds

120CC. PG is re-asserted when the device cools below to 100CC.

- Any FAULT condition causes PG to be de-asserted.

Over-Temperature

The regulator shuts down when the die temperature exceeds 150°C. Restart occurs when the IC has cooled by approximately 20°C.

Bypass Operation

In normal operation, the device automatically transitions from Boost Mode to Bypass Mode, if V_{IN} goes above target V_{OUT} . In Bypass Mode, the device fully enhances both Q1 and Q3 to provide a very low impedance path from V_{IN} to V_{OUT} . Entry to the Bypass Mode is triggered by condition where $V_{IN} > V_{OUT}$ and no switching has occurred during past 5 μ s. To soften the entry to Bypass Mode, Q3 is driven as a linear current source for the first 5 μ s. Bypass Mode exit is triggered when V_{OUT} reaches the target V_{OUT} voltage. During Automatic Bypass Mode, the device is short-circuit protected by voltage comparator tracking the voltage drop from V_{IN} to V_{OUT} ; if the drop exceeds 200 mV, FAULT is declared.

With sufficient load to enforce CCM operation, the Bypass Mode to Boost Mode transition occurs at the target V_{OUT} . The corresponding input voltage at the transition point is:

$$V_{IN} \leq V_{OUT} + I_{LOAD} * (DCR_L + R_{DS(ON)P}) \parallel R_{DS(ON)BYP} \quad (\text{eq. 1})$$

The Bypass Mode entry threshold has 25 mV hysteresis imposed at V_{OUT} to prevent cycling between modes. The

transition from Boost Mode to Bypass Mode occurs at the target $V_{OUT}+25$ mV. The corresponding input voltage is:

$$V_{IN} \geq V_{OUT} + 25\text{mV} + I_{LOAD} * (DCR_L + R_{DS(ON)P}) \quad (\text{eq. 2})$$

Forced Bypass

Entry to Forced Bypass Mode initiates with a current limit on Q3 and then proceeds to a true bypass state. To prevent reverse current to the battery, the device waits until output discharges below V_{IN} before entering Forced Bypass Mode.

After the transition is complete, most of the internal circuitry is disabled to minimize quiescent current draw. Short-circuit, UVLO, output OVP and over-temperature protections are inactive in Forced Bypass Mode.

In Forced Bypass Mode, V_{OUT} can follow V_{IN} below $V_{OUT(MIN)}$.

VSEL

V_{SEL} can be asserted in anticipation of a positive load transient. Raising V_{SEL} increases $V_{OUT(MIN)}$ by a fixed amount and V_{OUT} is stepped to the corresponding target output voltage in 20 μ s. The functionality can also be utilized to mitigate undershoot during severe line transients, while minimizing V_{OUT} during more benign operating conditions to save power.

EN

Setting the EN pin voltage below 0.4 V disables the part. Placing the voltage above 1.2 V enables the part. Do not connect the EN pin to V_{IN} . A logic voltage of 1.8 V should control the EN pin and enable / disable the device. The EN pin should be pulled HIGH after the V_{IN} voltage has reached a minimum voltage of 2.3 V.

APPLICATION INFORMATION

Output Capacitance (C_{OUT})

Stability

The effective capacitance (C_{EFF}) of small, high-value, ceramic capacitors decreases as bias voltage increases. FAN48630J is guaranteed for stable operation with the minimum value of C_{EFF} (C_{EFF(MIN)}) outlined in Table 11.

Table 11. Minimum C_{EFF} Required for Stability

Operating Conditions		C _{EFF(MIN)} (μF)
V _{OUT} (V)	I _{LOAD} (mA)	
3.15	0 to 1500	15

C_{EFF} varies with manufacturer, material, and case size.

Inductor Selection

Recommended nominal inductance value is 0.47 μH.

FAN48630J employs valley-current limiting; peak inductor current can reach 3.8 A for a short duration during overload conditions. Saturation effects cause the inductor current ripple to become higher under high loading as only valley of the inductor current ripple is controlled.

A 0.33 μH inductor can be used for improved transient performance.

Startup

Input current limiting is in effect during soft-start, which limits the current available to charge C_{OUT} and any additional capacitance on the V_{OUT} line. If the output fails to achieve regulation within the limits described in the Startup section, a FAULT occurs, causing the circuit to shut down then restart after 20 ms. If the total combined output capacitance is very high, the circuit may not start on the first attempt, but eventually achieves regulation if no load is

present. If a high-current load and high capacitance are both present during soft-start, the circuit may fail to achieve regulation and continually attempts soft-start, only to have the output capacitance discharged by the load when in a FAULT state.

Output Voltage Ripple

Output voltage ripple is inversely proportional to C_{OUT}. During t_{ON}, when the boost switch is on, all load current is supplied by C_{OUT}. Output ripple is calculated as:

$$V_{RIPPLE(P-P)} = t_{ON} * \frac{I_{LOAD}}{C_{OUT}} \quad (eq. 3)$$

and

$$t_{ON} = t_{SW} * D = t_{SW} * \left(1 - \frac{V_{IN}}{V_{OUT}}\right) \quad (eq. 4)$$

therefore:

$$V_{RIPPLE(P-P)} = t_{SW} * \left(1 - \frac{V_{IN}}{V_{OUT}}\right) * \frac{I_{LOAD}}{C_{OUT}} \quad (eq. 5)$$

and

$$t_{SW} = \frac{1}{f_{SW}} \quad (eq. 6)$$

Layout Recommendations

The layout recommendations below highlight various top-copper pours using different colors.

To minimize spikes at V_{OUT}, C_{OUT} must be placed as close as possible to PGND and V_{OUT}, as shown in Figure 22.

For thermal reasons, it is suggested to maximize the pour area for all planes other than SW. Especially the ground pour should be set to fill all available PCB surface area and tied to internal layers with a cluster of thermal vias.

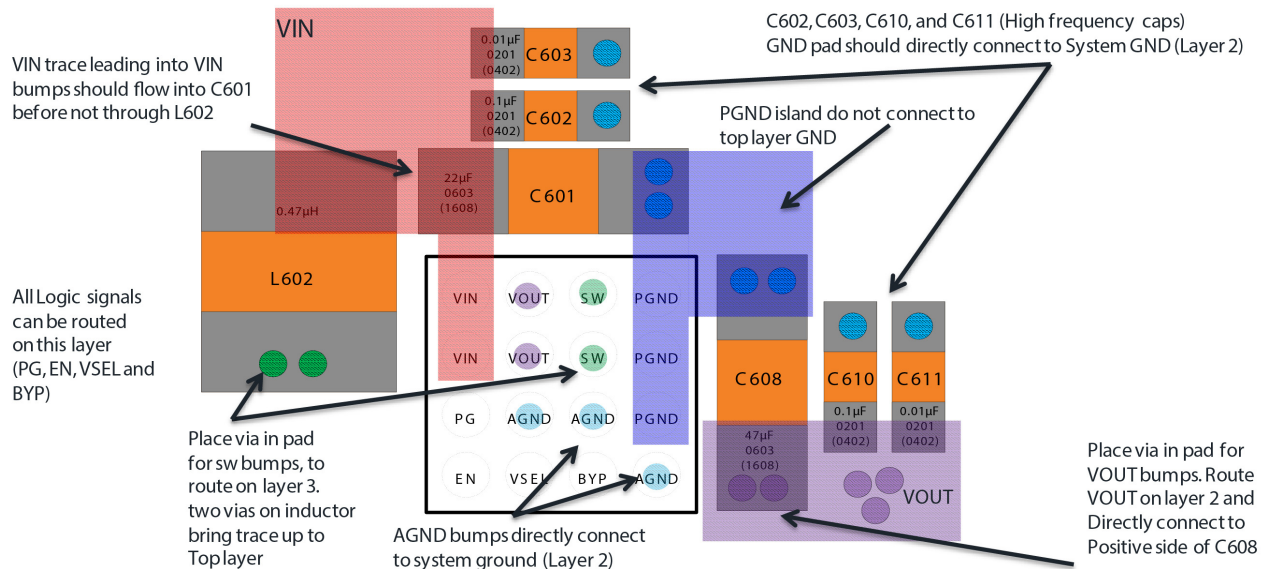


Figure 22. Top Layer

FAN48630J

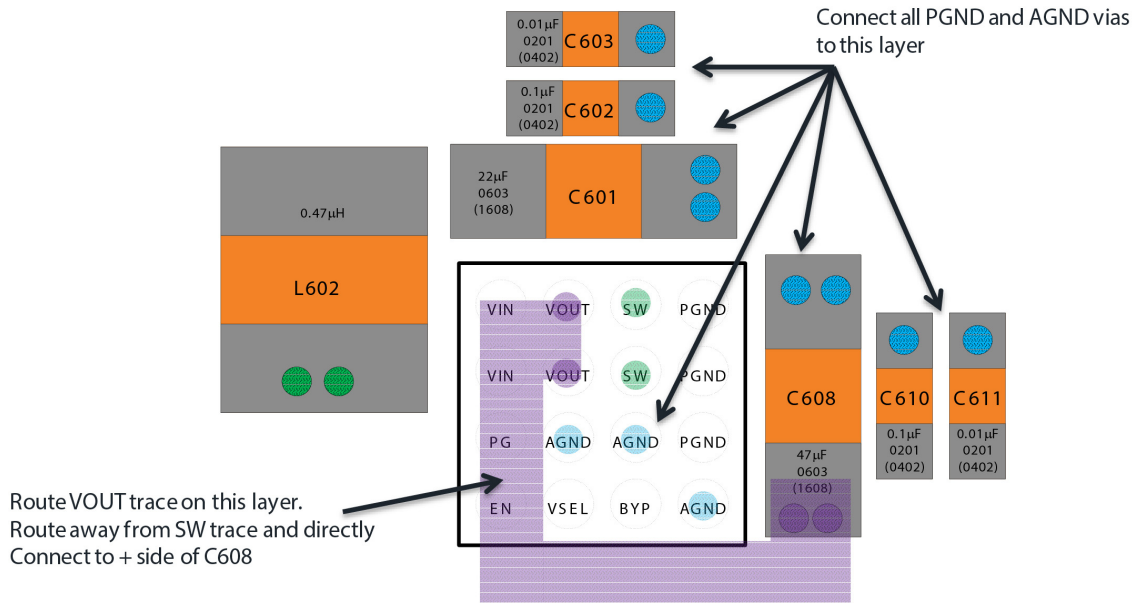


Figure 23. Layer 2

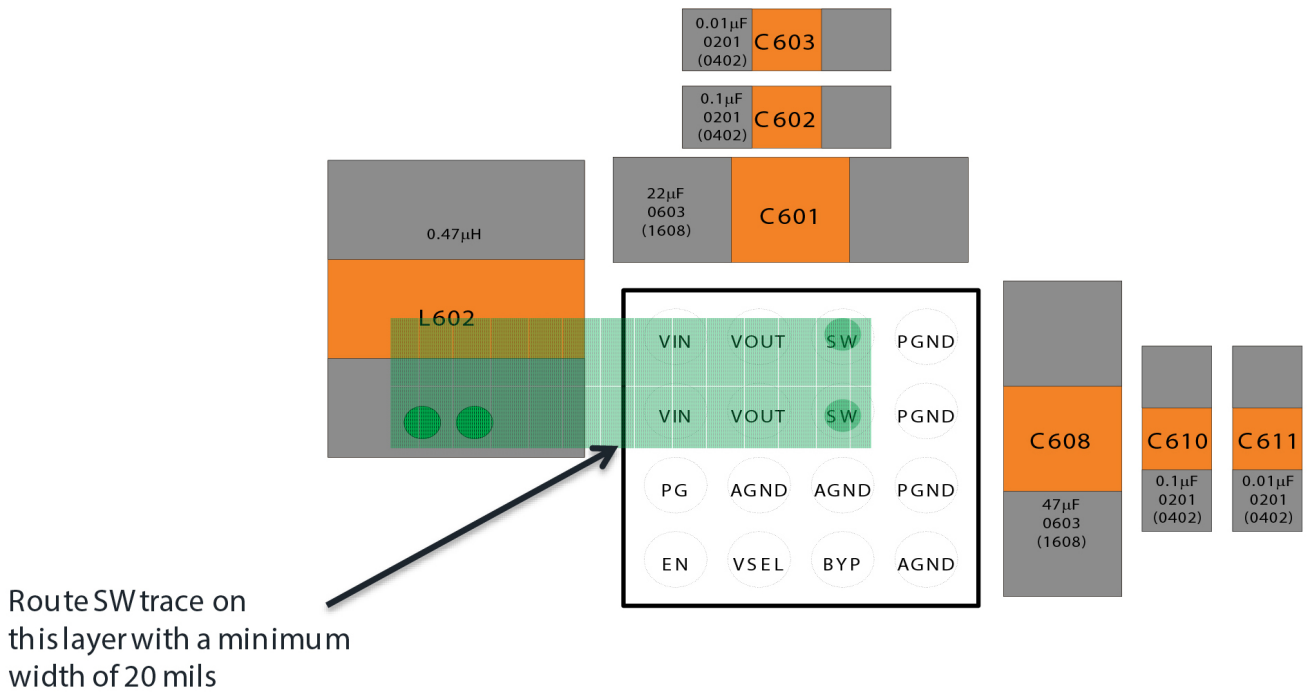


Figure 24. Layer 3

Table 12. PRODUCT-SPECIFIC DIMENSIONS

Product	D	E	X	Y
FAN48630BUC31JX	1.780 ± 0.030	1.780 ± 0.030	0.290	0.290

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MECHANICAL CASE OUTLINE

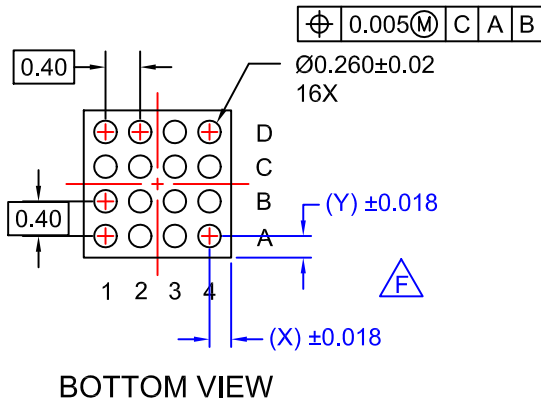
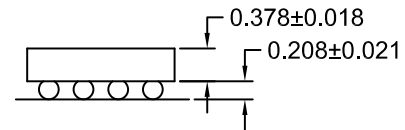
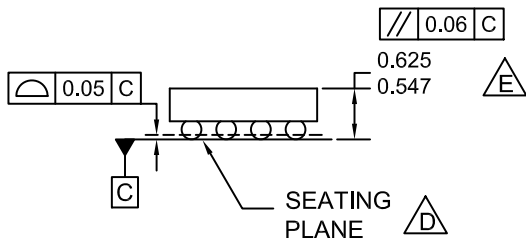
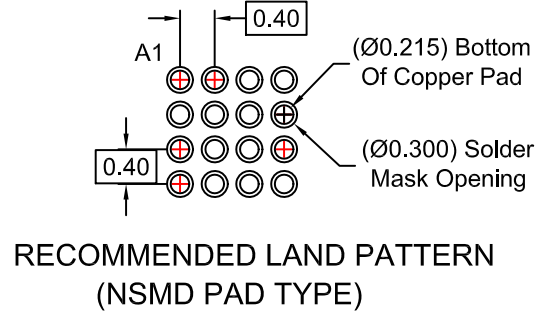
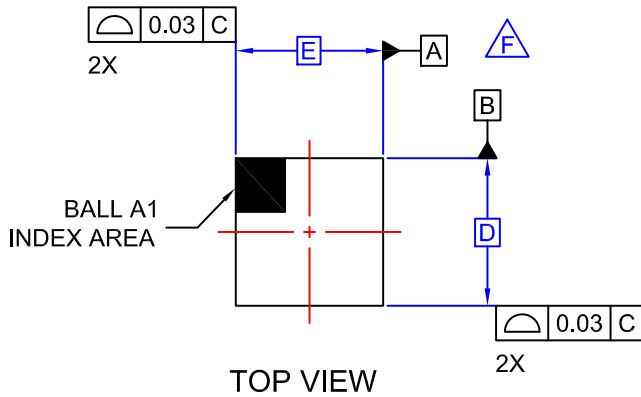
PACKAGE DIMENSIONS

ON Semiconductor®



WLCSP16 1.78x1.78x0.586
CASE 567SY
ISSUE O

DATE 30 NOV 2016



NOTES

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
- △ D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE NOMINAL HEIGHT IS 586 ± 39 MICRONS (547-625 MICRONS).
- △ F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

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